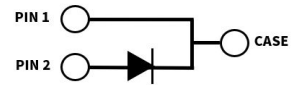


C4D20120A

4th Generation 1200 V, 20 A Silicon Carbide Schottky Diode

Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.



Package Types: TO-220-2
Marking: C4D20120

Wolfspeed, Inc. is in the process of rebranding its products and related materials pursuant to the entity name change from Cree, Inc. to Wolfspeed, Inc. During this transition period, products received may be marked with either the Cree name and/or logo or the Wolfspeed name and/or logo.

Features

- Low Forward Voltage (V_F) Drop with Positive Temperature Coefficient
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior

Typical Applications

- Industrial Switched Mode Power Supplies
- Uninterruptible & AUX Power Supplies
- Boost for PFC & DC-DC Stages
- Solar Inverters

Maximum Ratings ($T_c = 25^\circ\text{C}$ Unless Otherwise Specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes
Repetitive Peak Reverse Voltage	V_{RRM}	1200	V		
DC Blocking Voltage	V_{DC}	1200			
Continuous Forward Current	I_F	54.5	A	$T_c = 25^\circ\text{C}$	Fig. 3
		26		$T_c = 135^\circ\text{C}$	
		20		$T_c = 150^\circ\text{C}$	
Repetitive Peak Forward Surge Current	I_{FRM}	91		$T_c = 25^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$	
		61		$T_c = 110^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$	
Non-Repetitive Forward Surge Current	I_{FSM}	130		$T_c = 25^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$	Fig. 8
		110		$T_c = 110^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$	
Non-Repetitive Peak Forward Surge Current	$I_{F,Max}$	1150		$T_c = 25^\circ\text{C}, t_p = 10 \mu\text{s}, \text{Pulse}$	
		950		$T_c = 110^\circ\text{C}, t_p = 10 \mu\text{s}, \text{Pulse}$	
Power Dissipation	P_{tot}	250	W	$T_c = 25^\circ\text{C}$	Fig. 4
		112.5		$T_c = 110^\circ\text{C}$	
i^2t Value	$\int i^2t$	84.5	A^2s	$T_c = 25^\circ\text{C}, t_p = 10 \text{ ms}$	
		60.5		$T_c = 110^\circ\text{C}, t_p = 10 \text{ ms}$	



Electrical Characteristics

Parameter	Symbol	Typ.	Max.	Unit	Test Conditions	Notes
Forward Voltage	V_F	1.5	1.8	V	$I_F = 20\text{ A}, T_J = 25\text{ }^{\circ}\text{C}$	Fig. 1
		2.2	3		$I_F = 20\text{ A}, T_J = 175\text{ }^{\circ}\text{C}$	
Reverse Current	I_R	35	200	μA	$V_R = 1200\text{ V}, T_J = 25\text{ }^{\circ}\text{C}$	Fig. 2
		65	400		$V_R = 1200\text{ V}, T_J = 175\text{ }^{\circ}\text{C}$	
Total Capacitive Charge	Q_C	99		nC	$V_R = 800\text{ V}, T_J = 25\text{ }^{\circ}\text{C}$	Fig. 5
Total Capacitance	C	1500		pF	$V_R = 0\text{ V}, T_J = 25\text{ }^{\circ}\text{C}, f = 1\text{ MHz}$	Fig. 6
		93			$V_R = 400\text{ V}, T_J = 25\text{ }^{\circ}\text{C}, f = 1\text{ MHz}$	
		67			$V_R = 800\text{ V}, T_J = 25\text{ }^{\circ}\text{C}, f = 1\text{ MHz}$	
Capacitance Stored Energy	E_C	28		μJ	$V_R = 800\text{ V}$	Fig. 7

Notes:
SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

Parameter	Symbol	Value	Unit	Notes
Thermal Resistance, Junction to Case (Typical)	$R_{\theta, JC (TYP)}$	0.6	$^{\circ}\text{C} / \text{W}$	
Junction Temperature	T_J	-55 to +175	$^{\circ}\text{C}$	
Case & Storage Temperature	T_C	-55 to +175		
TO-220 Mounting Torque	-	1	Nm	M3 Screw
		8.8	lbf-in	6-32 Screw

Typical Performance

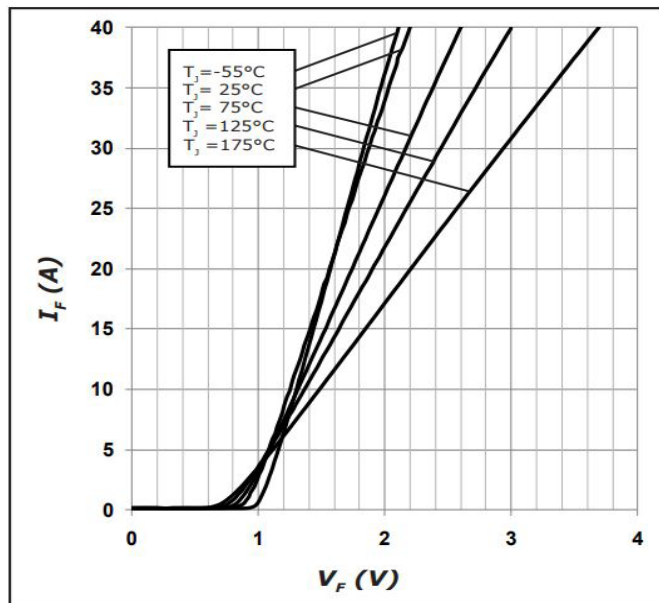


Figure 1
Forward Characteristics

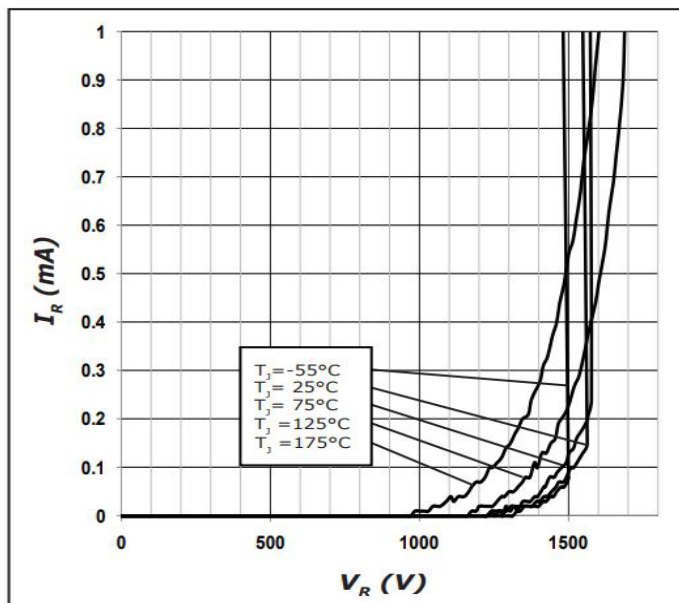


Figure 2
Reverse Characteristics

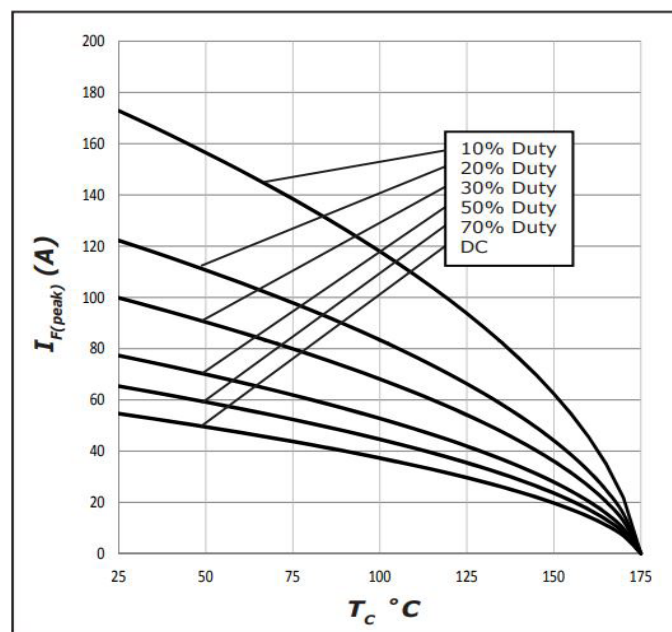


Figure 3
Current Derating

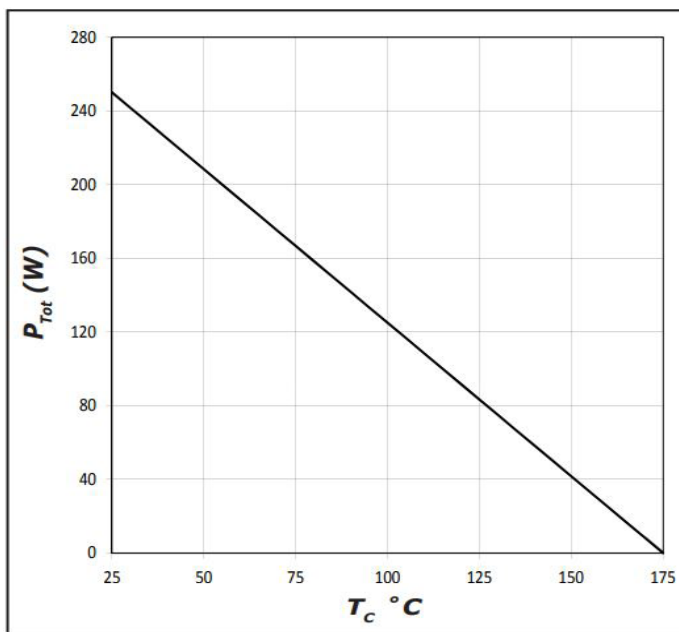
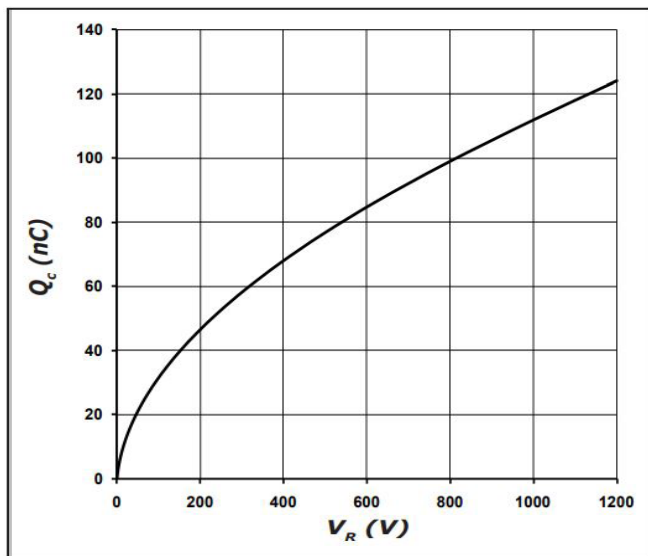
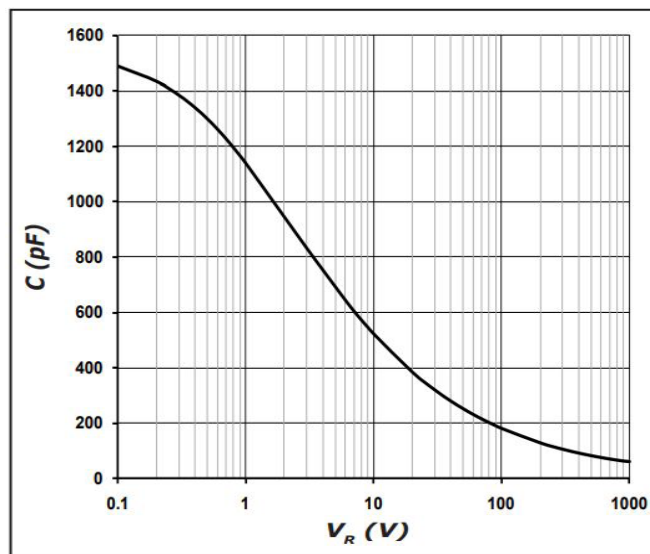


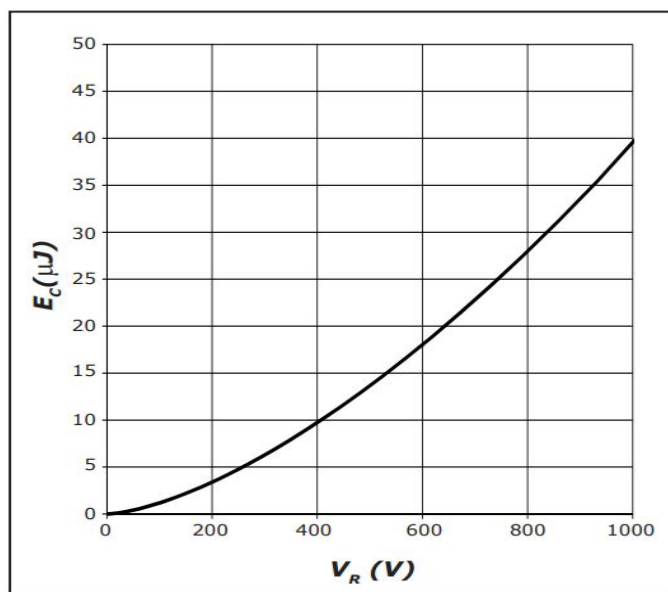
Figure 4
Power Derating

**Figure 5**

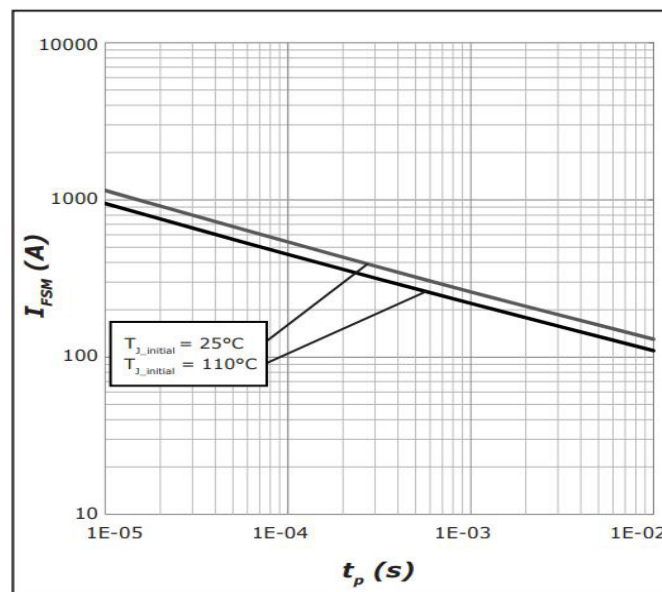
Total Capacitance vs. Reverse Voltage

**Figure 6**

Capacitance vs. Reverse Voltage

**Figure 7**

Capacitance Stored Energy

**Figure 8**Non-Repetitive Peak Forward Surge Current
versus Pulse Duration (sinusoidal waveform)

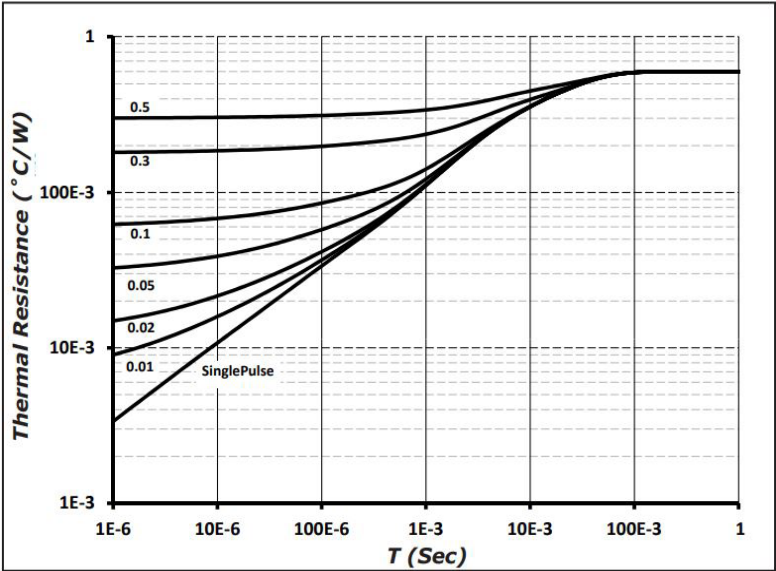
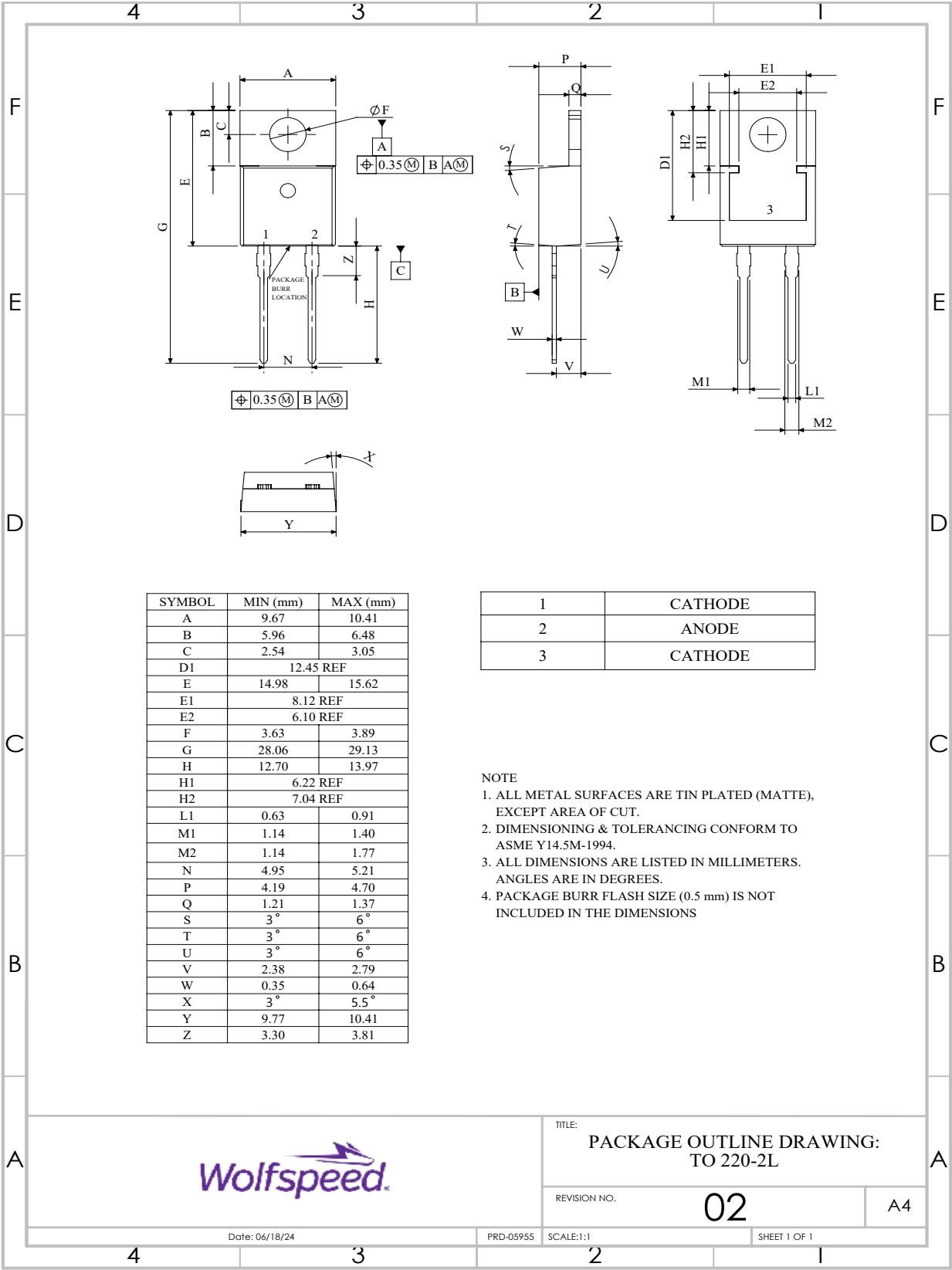


Figure 9
Transient Thermal Impedance

Package Dimensions & Pin-Out

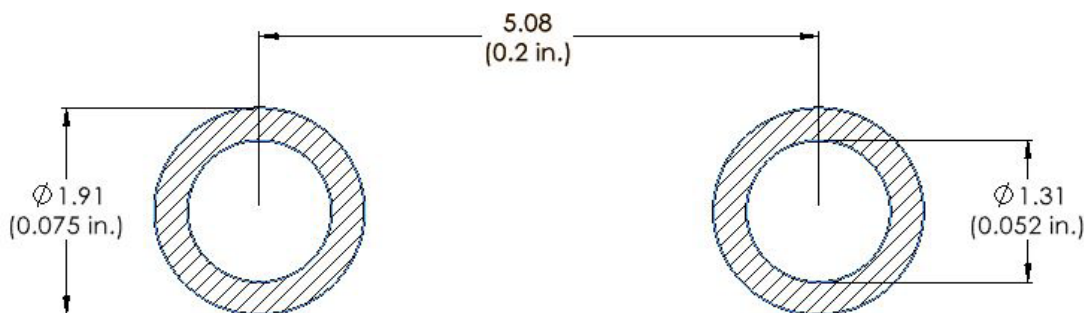
Package: TO-220-2





Recommended Solder Pad Layout

Primary dimensions shown in mm.
Learn more about recommended soldering profiles in [this application note](#).



Product Ordering Information

Order Number	Packing Type
C4D20120A	Tube

Learn more about power device packing & shipment information in [this application note](#).



Revision History

Document Version	Date of Release	Description of Changes
1	October-2016	Initial Release
6	March-2023	Update Package Drawing Update Landing Pad
7	July-2023	Updated Test Conditions of I_F and P_{tot} Added Package Marking Statement
8	October - 2024	Legal Disclaimer, POD, corrected package marking

Notes & Disclaimer

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